

Letter to the Editor Concerning “The Ground State of Epitaxial Germanene on Ag(111)”

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In a recent article by Zhang et al.¹ in *ACS Nano*, the authors write in the abstract of their article that there are many claims of the realization of germanene (the germanium analogue of graphene) but that no experimental evidence for the honeycomb structure of this two-dimensional material has been provided. This statement is incorrect. Already in 2014 we showed that germanene grown on Ge₂Pt has a honeycomb structure.² In Figure 1 a scanning tunneling

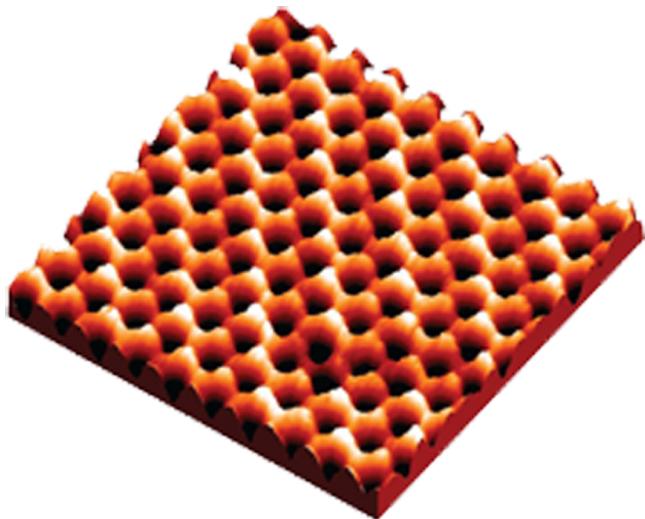


Figure 1. Scanning tunneling microscopy image (4.5 nm by 4.5 nm) of germanene on Ge₂Pt. The buckled honeycomb lattice of germanene is well-resolved. Sample bias –0.5 V, tunnel current 0.2 nA. The image has been taken from ref 2 with the permission of IOP.

image of germanene taken from the aforementioned reference is shown. We would like to emphasize that the observed buckling of germanene's honeycomb lattice^{2,3} is in agreement with theoretical predictions.^{4,5} Finally, Zhang et al.¹ also state in the introduction section of their article that the findings in many germanene manuscripts, including ours,² are questioned. This statement is also incorrect, as our work has not been questioned.

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